NSN 5961-00-531-3546

Yes - demil/mli

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-531-3546 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-71 **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Semiconductor Material:** Silicon all transistor **Voltage Rating In Volts Per Characteristic:** 50.0 drain to gate voltage all transistor and 50.0 gate to source voltage all transistor **Current Rating Per Characteristic:** 30.00 milliamperes gate current all transistor and 8.00 milliamperes zero-gate-voltage drain current all transistor **Power Rating Per Characteristic:** 400.0 milliwatts total power dissipation all transistor **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 6 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/430 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**